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SCES415N-NOVEMBER 2002-REVISED DECEMBER 2013

Configurable Multiple-Function Gate

Check for Samples: SN74LVC1G58

FEATURES

- Available in the Texas Instruments NanoFree™ Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Supports Down Translation to V_{CC}
- Max t_{pd} of 6.3 ns at 3.3 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION

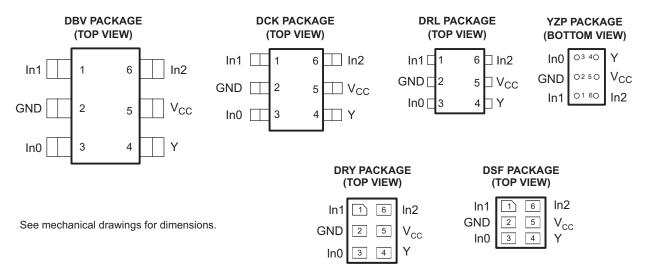
This configurable multiple-function gate is designed for 1.65-V to 5.5-V $\rm V_{\rm CC}$ operation.

The SN74LVC1G58 device features configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XOR, inverter, and noninverter. All inputs can be connected to V_{CC} or GND.

This device functions as an independent gate, but because of Schmitt action, it may have different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals.

NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



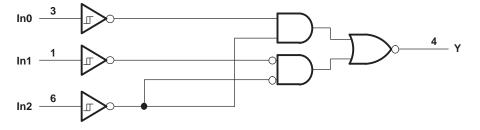
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

	Function Table										
	INPUTS	i	OUTPUT								
ln2	ln1	In0	Y								
L	L	L	L								
L	L	Н	н								
L	Н	L	L								
L	Н	Н	н								
Н	L	L	н								
н	L	Н	н								
н	Н	L	L								
Н	Н	Н	L								

Logic Diagram (Positive Logic)



Function Selection Table

LOGIC FUNCTION	FIGURE NO.
2-input AND with inverted input	Figure 2, Figure 3
2-input NAND	Figure 1
2-input NAND with both inputs inverted	Figure 4
2-input OR	Figure 4
2-input OR with both inputs inverted	Figure 1
2-input NOR with inverted input	Figure 2, Figure 3
2-input XOR	Figure 5



SN74LVC1G58

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Logic Configurations

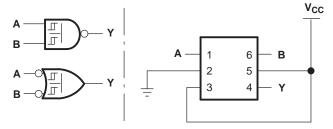


Figure 1. 2-Input NAND Gate

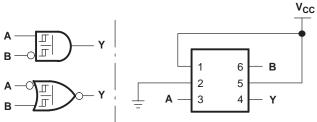
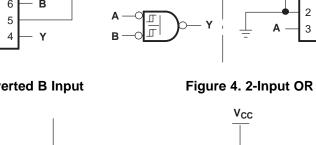


Figure 3. 2-Input AND Gate With Inverted B Input



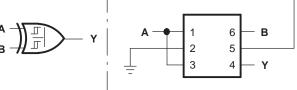


Figure 5. 2-Input XOR Gate

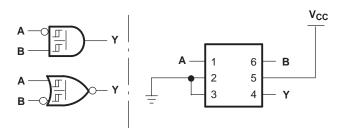


Figure 2. 2-Input AND Gate With Inverted A Input

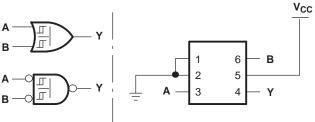


Figure 4. 2-Input OR Gate

NSTRUMENTS

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	6.5	V	
VI	Input voltage range ⁽²⁾		-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-im	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾				
Vo	Voltage range applied to any output in the high or	-0.5	V _{CC} + 0.5	V		
I _{IK}	Input clamp current	V ₁ < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
lo	Continuous output current	·		±50	mA	
	Continuous current through V _{CC} or GND			±100	mA	
		DBV package		165		
0		DCK package		259	1	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DRL package		142	°C/W	
		YZP package		123		
T _{stg}	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT			
V	Supply voltage	Operating	1.65	5.5	V			
V _{CC}	Supply voltage	Data retention only	1.5	1.5				
VI	Input voltage		0	5.5	V			
Vo	Output voltage		0	V_{CC}	V			
		V _{CC} = 1.65 V		-4				
		$V_{CC} = 2.3 V$		-8				
I _{OH}	High-level output current	$V_{CC} = 3 V$		-16	–16 mA			
		$v_{CC} = 5 v$		-24				
		$V_{CC} = 4.5 V$		-32				
		$V_{CC} = 1.65 V$		4				
		$V_{CC} = 2.3 V$		8				
I _{OL}	Low-level output current	N 2V		16	mA			
		$V_{CC} = 3 V$		24				
		$V_{CC} = 4.5 V$		32				
T _A	Operating free-air temperature		-40	125	°C			

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS	v	–40°C	to 85°C	–40°C	to 125°C	UNI	
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	MIN	TYP ⁽¹⁾ MAX	UNI	
		1.65 V	0.79	1.16	0.79	1.16		
V _{T+}		2.3 V	1.11	1.56	1.11	1.56		
Positive-going input		3 V	1.5	1.87	1.5	1.87	V	
threshold voltage		4.5 V	2.16	2.74	2.16	2.74		
		5.5 V	2.61	3.33	2.61	3.33		
		1.65 V	0.35	0.62	0.35	0.62		
V _{T-} Negative-going input threshold voltage		2.3 V	0.58	0.87	0.58	0.87		
		3 V	0.84	1.19	0.84	1.19	V	
		4.5 V	1.41	1.9	1.41	1.9		
		5.5 V	1.87	2.29	1.87	2.29		
		1.65 V	0.3	0.62	0.3	0.62		
ΔV _T Hysteresis (V _{T+} – V _T _)		2.3 V	0.4	0.8	0.4	0.8		
		3 V	0.53	0.87	0.53	0.87	V	
		4.5 V	0.71	1.04	0.71	1.04		
		5.5 V	0.71	1.11	0.71	1.11		
	I _{OH} = −100 μA	1.65 V to 5.5 V	V _{CC} - 0.1		V _{CC} - 0.1			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		1.2			
M	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		1.9		V	
V _{OH}	I _{OH} = -16 mA	3 V	2.4		2.4			
	$I_{OH} = -24 \text{ mA}$	3 V	2.3		2.3			
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8		3.8			
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1		0.1		
	$I_{OL} = 4 \text{ mA}$	1.65 V		0.45		0.45		
V	I _{OL} = 8 mA	2.3 V		0.3		0.3	V	
V _{OL}	I _{OL} = 16 mA	3 V		0.4		0.45	v	
	I _{OL} = 24 mA	3 V		0.55		0.55		
	I _{OL} = 32 mA	4.5 V		0.55		0.58		
I _I	$V_1 = 5.5 V \text{ or GND}$	0 to 5.5 V		±1		±1	μA	
l _{off}	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	0		±10		±10	μA	
I _{CC}	$V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$	1.65 V to 5.5 V		10		10	μA	
ΔI_{CC}	One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND	3 V to 5.5 V		500		500	μA	
Ci	$V_I = V_{CC}$ or GND	3.3 V		3.5			pF	

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 6)

			SN74LVC1G58 -40°C to 85°C								
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Any In	Y	3.2	14.4	2	8.3	1.5	6.3	1.1	5.1	ns

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 6)

PARAMETER			SN74LVC1G58 -40°C to 125°C								
	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Any In	Y	3.2	16.4	2	9.3	1.5	7.3	1.1	6.1	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{cc} = 5 V TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	22	22	23	24	pF



SN74LVC1G58

٧ı

0 V

٧ı

0 V

VI

0 V

VOL

VOH

≈0 V

V_{LOAD}/2

 V_{M}

– t_{PLZ}

Voi + V/

t_{PHZ}

 $V_{OH} - V_{\Delta}$

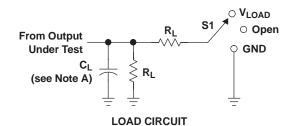
VOLTAGE WAVEFORMS

ENABLE AND DISABLE TIMES

LOW- AND HIGH-LEVEL ENABLING

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Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

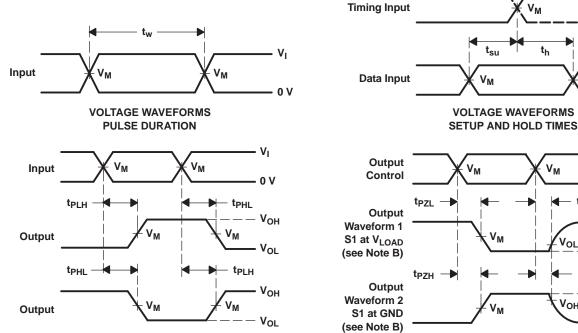
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VM

t_h

Vм

	INF	PUTS		N	•	-	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	V_{Δ}
1.8 V \pm 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- H. All parameters and waveforms are not applicable to all devices.

Figure 6. Load Circuit and Voltage Waveforms

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REVISION HISTORY	
Changes from Revision K (January 2007) to Revision L	Page
Added additional package options in the Ordering Information table.	1
Added DRY and DSF packages to datasheet.	1
 Changes from Revision L (October 2011) to Revision M Removed Ordering Information table, package updates now included in Package Ordering Addendum. 	Page 1
Changes from Revision M (April 2013) to Revision N	Page
Updated document to new TI data sheet format.	1
Updated Features.	1
Added ESD warning.	2

Updated operating temperature range.

4



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G58DBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C585, C58R)	Samples
SN74LVC1G58DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CP5, CPF, CPK, CP R)	Samples
SN74LVC1G58DCKRE4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CPF	Samples
SN74LVC1G58DCKRG4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CPF	Samples
SN74LVC1G58DRLR	ACTIVE	SOT-5X3	DRL	6	4000	RoHS & Green	NIPDAU SN NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(1K3, CP7, CPR)	Samples
SN74LVC1G58DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СР	Samples
SN74LVC1G58DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СР	Samples
SN74LVC1G58DSF2	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СР	Samples
SN74LVC1G58DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СР	Samples
SN74LVC1G58YZPR	ACTIVE	DSBGA	YZP	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CPN	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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PACKAGE OPTION ADDENDUM

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G58DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G58DCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74LVC1G58DCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G58DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
SN74LVC1G58DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74LVC1G58DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G58DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3
SN74LVC1G58DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G58YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1



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PACKAGE MATERIALS INFORMATION

23-Mar-2024



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74LVC1G58DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0	
SN74LVC1G58DCKR	SC70	DCK	6	3000	210.0	185.0	35.0	
SN74LVC1G58DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0	
SN74LVC1G58DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0	
SN74LVC1G58DRY2	SON	DRY	6	5000	184.0	184.0	19.0	
SN74LVC1G58DRYR	SON	DRY	6	5000	184.0	184.0	19.0	
SN74LVC1G58DSF2	SON	DSF	6	5000	184.0	184.0	19.0	
SN74LVC1G58DSFR	SON	DSF	6	5000	184.0	184.0	19.0	
SN74LVC1G58YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0	

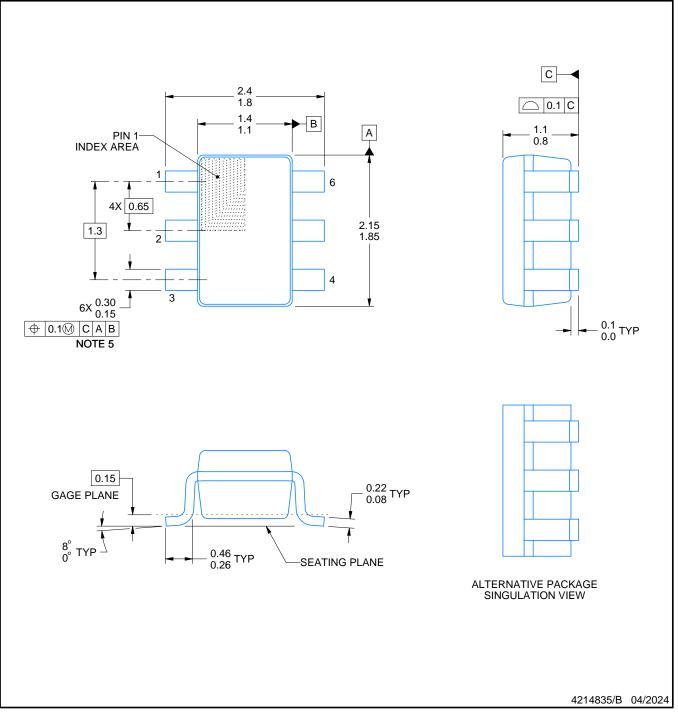
DCK0006A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 Falls within JEDEC MO-203 variation AB.

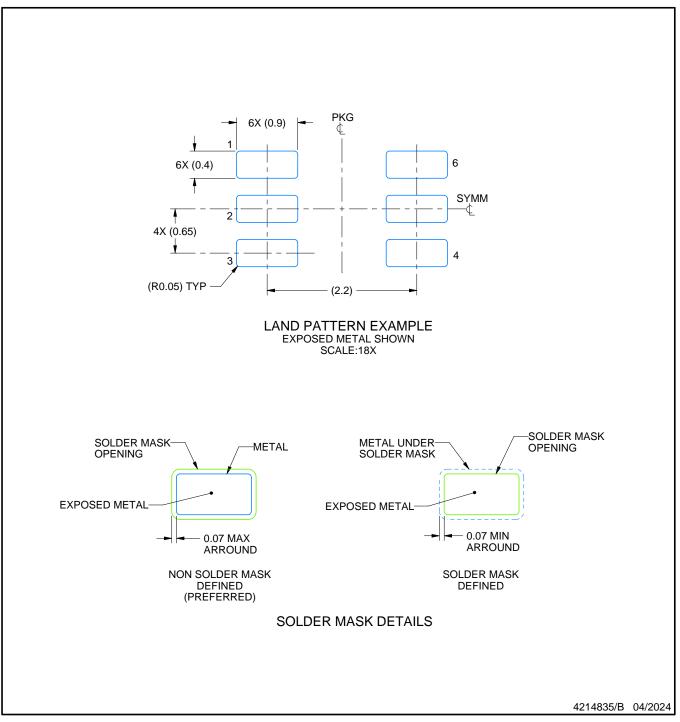


DCK0006A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0006A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

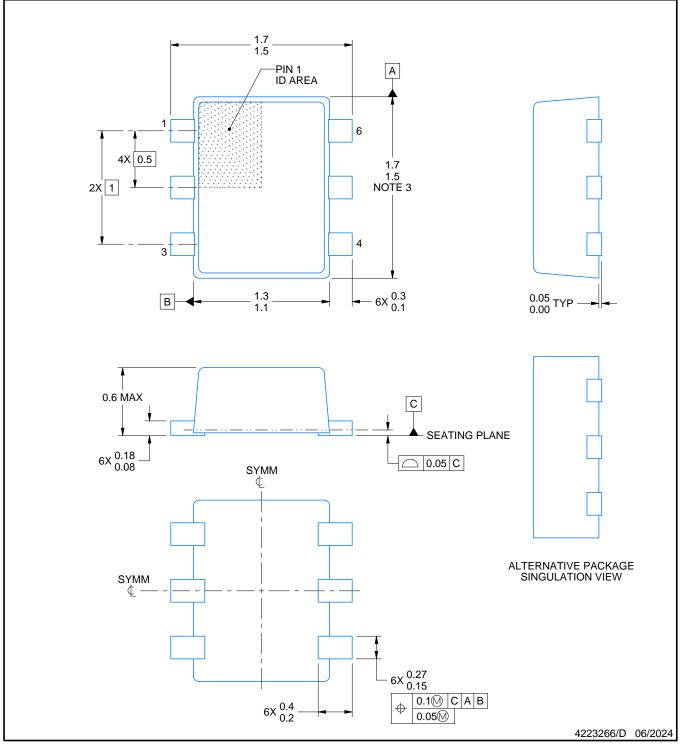
DRL0006A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-293 Variation UAAD

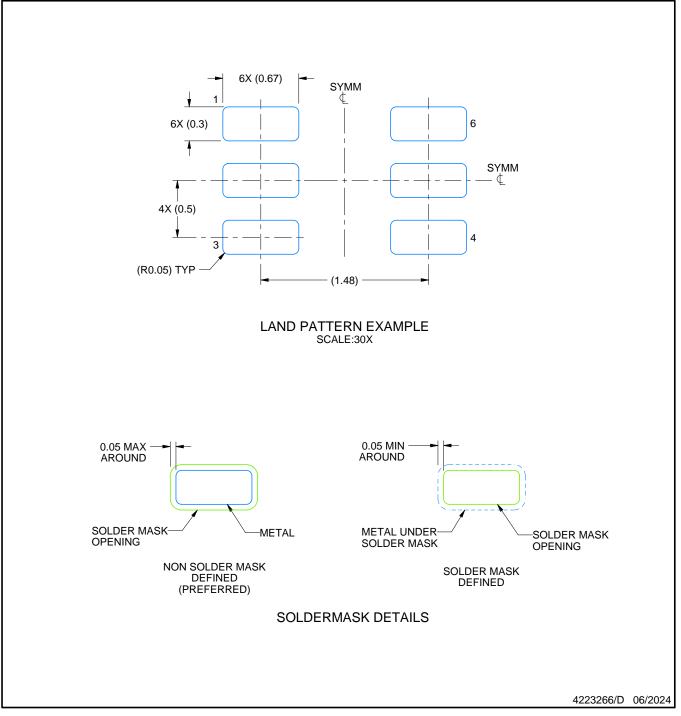


DRL0006A

EXAMPLE BOARD LAYOUT

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
 7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

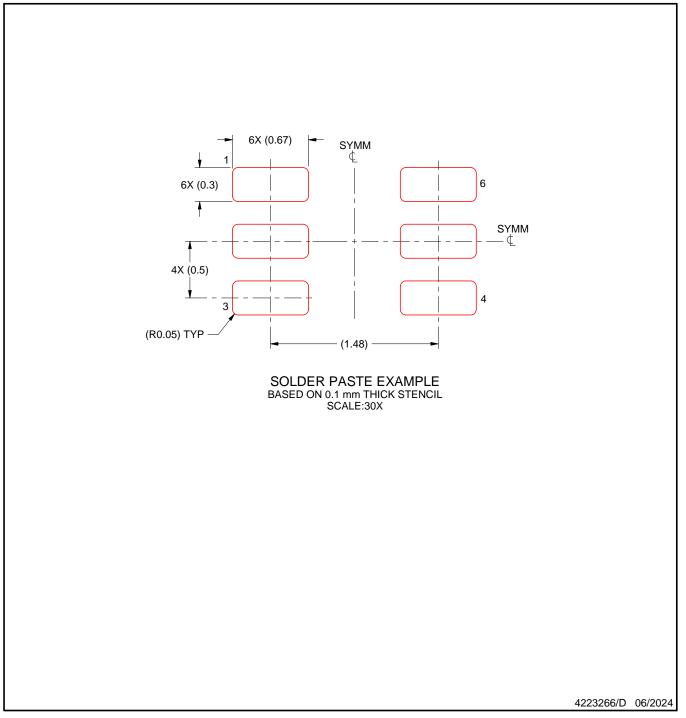


DRL0006A

EXAMPLE STENCIL DESIGN

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



GENERIC PACKAGE VIEW

USON - 0.6 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4207181/G

DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.



DRY0006A

EXAMPLE BOARD LAYOUT

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



DRY0006A

EXAMPLE STENCIL DESIGN

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DSF0006A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.



DSF0006A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



DSF0006A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



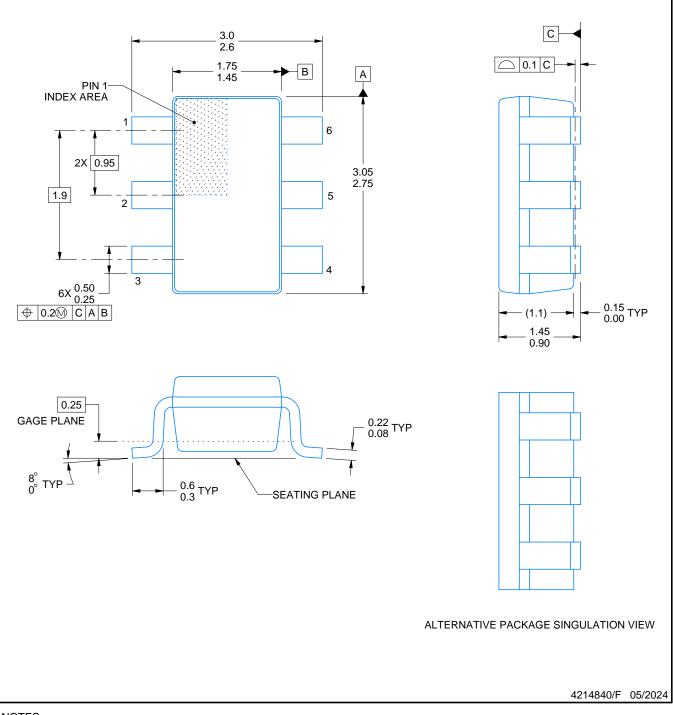
DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.

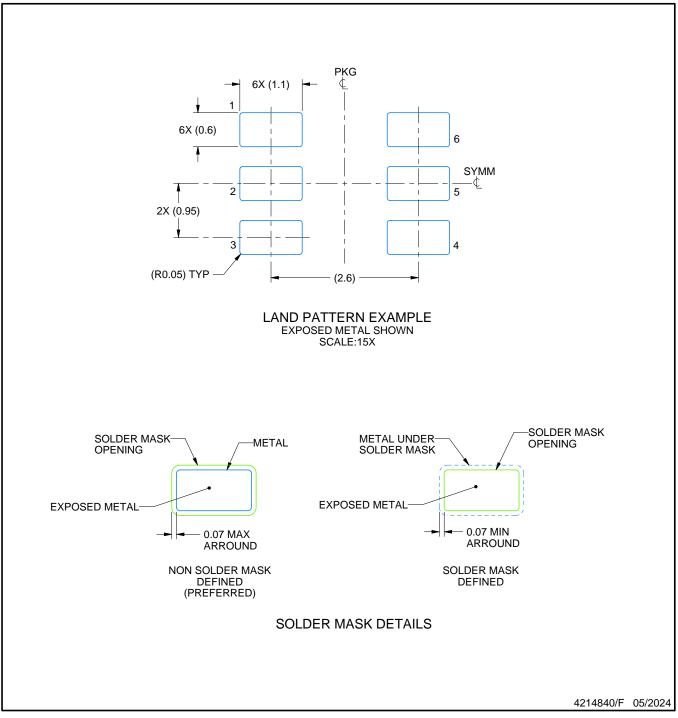


DBV0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

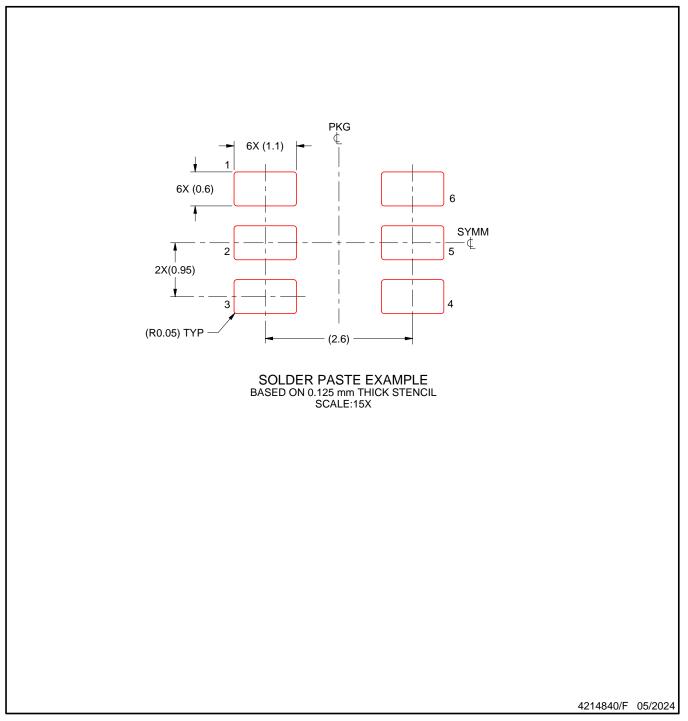


DBV0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



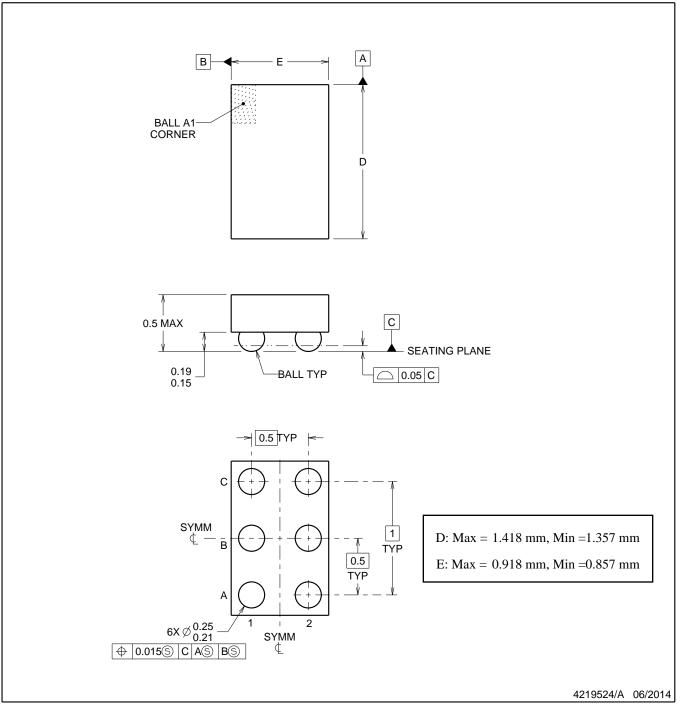
YZP0006



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

NanoFree Is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.



YZP0006

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).



YZP0006

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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